



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Eliyahou Harari et al.
Assignee: SanDisk Corporation
Title: Multi-State Non-Volatile Integrated Circuit Memory Systems That Employ Dielectric Storage Elements
Application No.: 10/002,696 Filing Date: October 31, 2001
Examiner: Weiss, Howard Group Art Unit: 2814
Docket No.: M-12336 US Conf. No.: 4652

San Francisco, California
November 12, 2002

COMMISSIONER FOR PATENTS
WASHINGTON, D. C. 20231

AMENDMENT

Sir:

In response to the Office Action dated July 24, 2002, please amend the above-identified patent application as follows:

IN THE CLAIMS:

Cancel non-elected claims 1 – 12, without prejudice to pursuing them in another application. Also cancel claims 14 and 24, without prejudice.

Certain claims are being amended and new claims are being added, as set forth in detail below. All of the claims remaining in the present application after this Amendment are given in the attached "Text of All Application Claims After Amendment."

Please amend claims 13, 15 – 23 and 25 to read as follows (details of these amendments are shown in the attached "Amended Claims with Markings to Show Changes Made"):

LAW OFFICES OF
SKJERNEN MORRILL LLP
3 EMBARCADERO CENTER
SUITE 200
SAN FRANCISCO, CA 94111
(415) 217-6000
FAX: (415) 435-0046

00000002 192386 10002696

10.00 CH

903623 v1

Application No.: 10/002,696